

REVISIONS																			
LTR	DESCRIPTION	DATE (YR-MO-DA)	APPROVED																
A	Add figure 4. Technical changes to 1.3, 1.4, table I, and table II. Change terminal connections. Editorial changes throughout.	89 AUG 18	<i>M.D. Lyle</i>																

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REV STATUS OF SHEETS	REV	A	A	A	A	A	A	A	A	A	A	A	A	A	A					
	SHEET	1	2	3	4	5	6	7	8	9	10	11	12	13						

PMIC N/A	PREPARED BY <i>Marcus L. Poelking</i> CHECKED BY <i>Marcus L. Poelking</i> APPROVED BY <i>M.D. Lyle</i>	DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444
STANDARDIZED MILITARY DRAWING THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE AMSC N/A	DRAWING APPROVAL DATE 17 NOVEMBER 1987	MICROCIRCUIT, DIGITAL, ECL, 4 WIDE 4-3-3-3 INPUT OR-AND GATE, MONOLITHIC SILICON
	REVISION LEVEL A	SIZE A
		CAGE CODE 67268
	SHEET 1 OF 1	5962-87728

DESC FORM 193
SEP 87

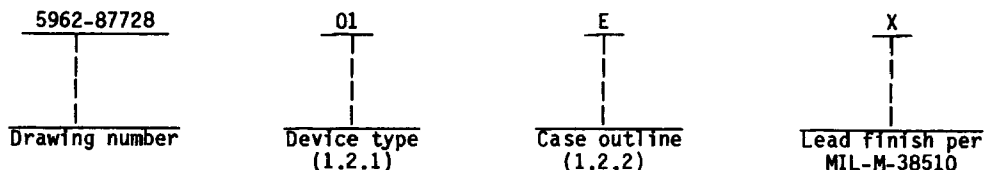
• U.S. GOVERNMENT PRINTING OFFICE: 1987 — 748-129/60911
5962-E1116-2

DISTRIBUTION STATEMENT A. Approved for public release; distribution is unlimited.

1. SCOPE

1.1 Scope. This drawing describes device requirements for class B microcircuits in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices".

1.2 Part number. The complete part number shall be as shown in the following example:



1.2.1 Device type. The device type shall identify the circuit function as follows:

Device type	Generic number	Circuit function
01	10H519	4-wide 4-3-3-3 input OR-AND gate

1.2.2 Case outlines. The case outlines shall be as designated in appendix C of MIL-M-38510, and as follows:

Outline letter	Case outline
E	D-2 (16-lead, .840" x .310" x .200"), dual-in-line package
F	F-5 (16-lead, .440" x .285" x .085"), flat package
2	C-2 (20-terminal, .358" x .358" x .100"), square chip carrier package

1.3 Absolute maximum ratings.

Supply voltage range (V_{EE})	-8.0 V dc to 0.0 V dc
Input voltage range	-5.2 V dc to 0.0 V dc
Storage temperature range	-65°C to +165°C
Lead temperature (soldering, 10 seconds)	+300°C
Junction temperature (T_J)	+165°C
Maximum power dissipation (P_D)	441 mW
Thermal resistance, junction-to-case (θ_{JC})	See MIL-M-38510, appendix C

1.4 Recommended operating conditions.

Supply voltage range (V_{EE})	-5.46 V dc to -4.94 V dc
Supply voltage range (V_{CC})	-0.02 V dc to +0.02 V dc or +1.98 V dc to +2.02 V dc
Ambient operating temperature range (T_A)	-55°C to +125°C
Minimum high level input voltage (V_{IH}):	
$T_A = +25^\circ\text{C}$	-0.780 V
$T_A = +125^\circ\text{C}$	-0.650 V
$T_A = -55^\circ\text{C}$	-0.840 V
Maximum low level input voltage (V_{IL})	-1.950 V

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2. APPLICABLE DOCUMENTS

2.1 Government specification and standard. Unless otherwise specified, the following specification and standard, of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

SPECIFICATION

MILITARY

MIL-M-38510 - Microcircuits, General Specification for.

STANDARD

MILITARY

MIL-STD-883 - Test Methods and Procedures for Microelectronics.

(Copies of the specification and standard required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.

3. REQUIREMENTS

3.1 Item requirements. The individual item requirements shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein.

3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-M-38510 and herein.

3.2.1 Terminal connections. The terminal connections shall be as specified on figure 1.

3.2.2 Truth table. The truth table shall be as specified on figure 2.

3.2.3 Logic diagram. The logic diagram shall be as specified on figure 3.

3.2.4 Test circuit and switching waveforms. The test circuit and switching waveforms shall be as specified on figure 4.

3.2.5 Case outlines. The case outlines shall be in accordance with 1.2.2 herein.

3.3 Electrical performance characteristics. Unless otherwise specified, the electrical performance characteristics are as specified in table I and apply over the full ambient operating temperature range.

3.4 Marking. Marking shall be in accordance with MIL-STD-883 (see 3.1 herein). The part shall be marked with the part number listed in 1.2 herein. In addition, the manufacturer's part number may also be marked as listed in 6.4 herein.

3.5 Certificate of compliance. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in 6.4. The certificate of compliance submitted to DESC-ECS prior to listing as an approved source of supply shall state that the manufacturer's product meets the requirements of MIL-STD-883 (see 3.1 herein) and the requirements herein.

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TABLE I. Electrical performance characteristics.

Test	Symbol	Conditions -55°C ≤ T _A ≤ +125°C unless otherwise specified	Group A subgroups	Limits		Unit		
				Min	Max			
Cases E, F, and 2		Quiescent tests 1/						
High level output voltage	V _{OH}	Outputs terminated through 100Ω to -2 V	V _{IH}	V _{IL}				
		V _{CC} = 0.0 V	-0.780	-1.950	1	-1.010	-0.780	V
		V _{EE} = -5.2 V	-0.650	-1.950	2	-0.860	-0.650	
		2/	-0.840	-1.950	3	-1.060	-0.840	
Low level output voltage	V _{OL}		-0.780	-1.950	1	-1.950	-1.580	V
			-0.650	-1.950	2	-1.950	-1.565	
			-0.840	-1.950	3	-1.950	-1.610	
High level threshold output voltage	V _{OHA}		-1.110	-1.480	1	-1.010	-0.780	V
			-0.960	-1.465	2	-0.860	-0.650	
			-1.160	-1.510	3	-1.060	-0.840	
Low level threshold output voltage	V _{OLA}		-1.110	-1.480	1	-1.950	-1.580	V
			-0.960	-1.465	2	-1.950	-1.565	
			-1.160	-1.510	3	-1.950	-1.610	
Power supply drain current 3/	I _{EE}	V _{EE} = -5.46 V V _{CC} = 0.0 V V _{IH} = -0.780 V at +25°C -0.650 V at +125°C -0.840 V at -55°C			1 2,3	-26 -29		mA
High level input current	I _{IH1}		All inputs except A		1 2,3		295 500	μA
	I _{IH2}		Input A		1 2,3		360 610	μA
Low level input current	I _{IL}	V _{EE} = -4.94 V V _{IL} = -1.950 V V _{CC} = 0.0 V	3/		1,3 2	0.5 0.3		μA
Functional tests		See 4.3.1c			7,8			
See footnotes at end of table.								
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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions -55°C < T _A < +125°C unless otherwise specified	Group A subgroups	Limits		Unit			
				Min	Max				
Cases E and F									
DC rapid tests <u>4/</u>									
			V _{IH}	V _{IL}					
High level output voltage	V _{OH}	Outputs terminated through 100Ω to -2 V V _{CC} = 0.0 V V _{EE} = -5.2 V <u>2/</u>	-0.787	-1.950	1	-1.016	-0.787	V	
			-0.657	-1.950	2	-0.867	-0.657		
			-0.847	-1.950	3	-1.067	-0.847		
Low level output voltage	V _{OL}		-0.787	-1.950	1	-1.950	-1.582	V	
			-0.657	-1.950	2	-1.950	-1.567		
			-0.847	-1.950	3	-1.950	-1.612		
High level threshold output voltage	V _{OHA}		-1.116	-1.482	1	-1.016	-0.787	V	
			-0.967	-1.467	2	-0.867	-0.657		
			-1.167	-1.512	3	-1.067	-0.847		
Low level threshold output voltage	V _{OLA}		-1.116	-1.482	1	-1.950	-1.582	V	
			-0.967	-1.467	2	-1.950	-1.567		
			-1.167	-1.512	3	-1.950	-1.612		
Power supply drain current <u>3/</u>	I _{EE}		V _{EE} = -5.46 V V _{CC} = 0.0 V V _{IH} = -0.780 V at +25°C -0.650 V at +125°C -0.840 V at -55°C			1 2,3	-25 -28		mA
High level input current	I _{IH1}			All inputs except A	1 2,3			280 485	μA
	I _{IH2}			Input A	1 2,3			345 595	μA
Low level input current	I _{IL}	V _{EE} = -4.94 V V _{IL} = -1.950 V V _{CC} = 0.0 V	<u>3/</u>	1,3 2	0.5 0.3			μA	
Functional tests		See 4.3.1c		7,8					

See footnotes at end of table.

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DEFENSE ELECTRONICS SUPPLY CENTER
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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions -55°C ≤ T _A ≤ +125°C unless otherwise specified	Group A subgroups	Limits		Unit		
				Min	Max			
Case 2 DC rapid tests 4/								
High level output voltage	V _{OH}	Outputs terminated through 100Ω to -2 V V _{CC} = 0.0 V V _{EE} = -5.2 V 2/	V _{IH}	V _{IL}				
			-0.791	-1.950	1	-1.020	-0.791	V
			-0.662	-1.950	2	-0.871	-0.662	
-0.852	-1.950		3	-1.071	-0.852			
Low level output voltage	V _{OL}		-0.791	-1.950	1	-1.950	-1.583	V
			-0.662	-1.950	2	-1.950	-1.569	
			-0.852	-1.950	3	-1.950	-1.614	
High level threshold output voltage	V _{OHA}		-1.120	-1.483	1	-1.020	-0.791	V
			-0.971	-1.469	2	-0.871	-0.662	
			-1.171	-1.514	3	-1.071	-0.852	
Low level threshold output voltage	V _{OLA}		-1.120	-1.483	1	-1.950	-1.583	V
			-0.971	-1.469	2	-1.950	-1.569	
			-1.171	-1.514	3	-1.950	-1.614	
Power supply drain current 3/	I _{EE}		V _{EE} = -5.46 V V _{CC} = 0.0 V V _{IH} = -0.780 V at +25°C -0.650 V at +125°C -0.840 V at -55°C			1 2,3	-25 -28	mA
High level input current	I _{IH1}			All inputs except A	1 2,3		280 485	μA
	I _{IH2}		Input A	1 2,3		345 595	μA	
Low level input current	I _{IL}	V _{EE} = -4.94 V V _{IL} = -1.950 V V _{CC} = 0.0 V	3/	1,3 2	0.5 0.3		μA	
Functional tests		See 4.3.1c		7,8				

See footnotes at end of table.

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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions -55°C < T _A < +125°C unless otherwise specified	Group A subgroups	Limits		Unit
				Min	Max	
Cases E, F, and 2 AC tests						
Transition time	t _{TLH} , t _{THL}	V _{EE} = -2.94 V V _{CC} = 2.0 V C _L < 5 pF Load all outputs 100Ω to ground See figure 4	9	0.60	2.00	ns
			10	0.60	2.30	
			11	0.60	1.90	
Propagation delay time, A to Y	t _{PHH1} , t _{PLL1}		9	0.75	2.25	ns
			10	0.60	2.55	
			11	0.75	2.20	
Propagation delay time, data inputs (excluding A) to Y	t _{PHH2} , t _{PLL2}		9	0.60	2.50	ns
			10	0.60	2.80	
			11	0.60	2.40	

- 1/ The quiescent limits are determined after a device has reached thermal equilibrium. This is defined as the reading taken with the device in a socket with > 500 LFPM of +25°C, +125°C, or -55°C (as applicable) air blowing on the unit in a transverse direction with power applied for at least 4 minutes before the reading is taken. This method was used for theoretical limit establishment only. All devices shall be tested to the delta V (rapid test) conditions specified herein. The rapid test method is an equivalent method of testing quiescent conditions.
- 2/ The high and low level output current varies with temperature and shall be calculated using the following formulas: $I_{OH} = (V_{OH} - 2 \text{ V})/100\Omega$ and $I_{OL} = (V_{OL} - 2 \text{ V})/100\Omega$.
- 3/ Although specified in the minimum column, the I_{EE} and I_{IL} limits shall not be exceeded in magnitude as a maximum value.
- 4/ The dc rapid test forcing functions and limits are used for all dc testing. These limits are determined for each device type based on the power dissipation and package type. The rapid test (delta V) limits and forcing functions are skewed allowing rapid testing to be performed at standard temperatures without the addition of delta T's.

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Case outlines	E	F	2
Terminal number	Terminal symbol		
1	V _{CC1}	D2	NC
2	Y	E2	V _{CC1}
3	G1	F2	Y
4	F1	V _{CC2}	G1
5	E1	V _{CC1}	F1
6	D1	Y	NC
7	C1	G1	E1
8	V _{EE}	F1	D1
9	B1	E1	C1
10	A	D1	V _{EE}
11	B2	C1	NC
12	C2	V _{EE}	B1
13	D2	B1	A
14	E2	A	B2
15	F2	B2	C2
16	V _{CC2}	C2	NC
17	---	---	D2
18	---	---	E2
19	---	---	F2
20	---	---	V _{CC2}

NC = No connection

FIGURE 1. Terminal connections.

FIGURE 1. Terminal connections.

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Inputs							Output
A	B	C	D	E	F	G	Y
L	L	L	X	X	X	X	L
X	X	X	L	L	L	L	L
All other combinations							H

L = Low level voltage
 H = High level voltage
 X = Irrelevant

FIGURE 2. Truth table.

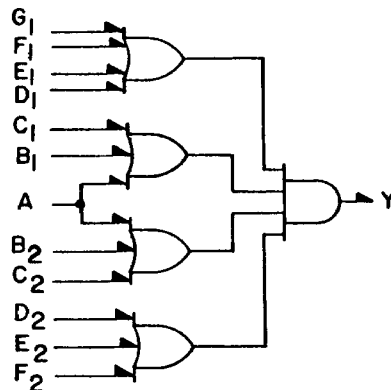
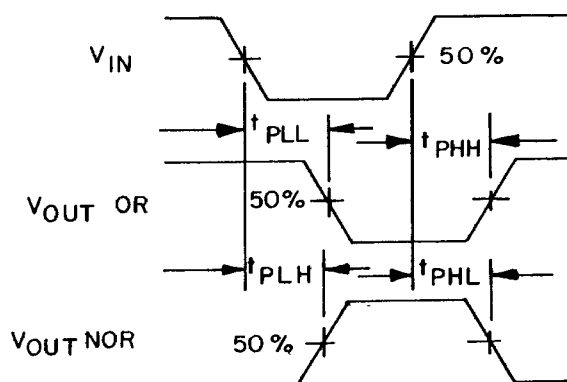
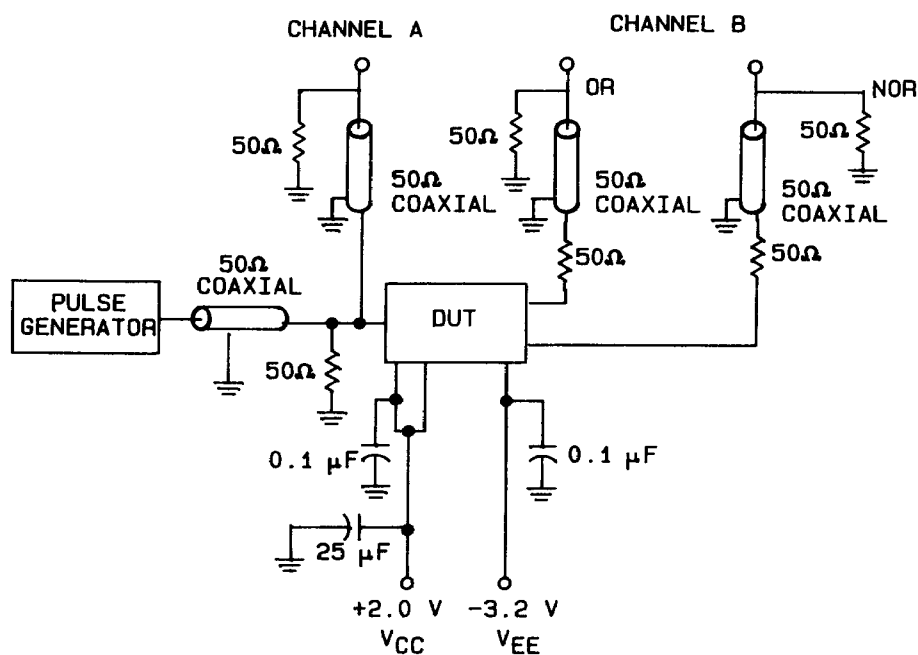


FIGURE 3. Logic diagram.

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NOTE: Pulse generator characteristics:
 PRR = 1 MHz, $t_{THL} = t_{TLH} = 2.0 \pm 0.2$ ns
 (20% to 80%), duty cycle = 50%.

FIGURE 4. Test circuit and switching waveforms.

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3.6 Certificate of conformance. A certificate of conformance as required in MIL-STD-883 (see 3.1 herein) shall be provided with each lot of microcircuits delivered to this drawing.

3.7 Notification of change. Notification of change to DESC-ECS shall be required in accordance with MIL-STD-883 (see 3.1 herein).

3.8 Verification and review. DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.

4. QUALITY ASSURANCE PROVISIONS

4.1 Sampling and inspection. Sampling and inspection procedures shall be in accordance with section 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein).

4.2 Screening. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:

a. Burn-in test, method 1015 of MIL-STD-883.

(1) Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).

(2) $T_A = +125^{\circ}\text{C}$, minimum.

b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.

4.3 Quality conformance inspection. Quality conformance inspection shall be in accordance with method 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.

4.3.1 Group A inspection.

a. Tests shall be as specified in table II herein.

b. Subgroups 4, 5, and 6 in table I, method 5005 of MIL-STD-883 shall be omitted.

c. Subgroups 7 and 8 tests shall verify the truth table specified on figure 2 herein.

4.3.2 Groups C and D inspections.

a. End-point electrical parameters shall be as specified in table II herein.

b. Steady-state life test conditions, method 1005 of MIL-STD-883.

(1) Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).

(2) $T_A = +125^{\circ}\text{C}$, minimum.

(3) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

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TABLE II. Electrical test requirements.

MIL-STD-883 test requirements	Subgroups (per method 5005, table I)
Interim electrical parameters (method 5004)	1
Final electrical test parameters (method 5004)	1*, 2, 3, 7*, 8, 9
Group A test requirements (method 5005)	1, 2, 3, 7, 8, 9, 10, 11
Groups C and D end-point electrical parameters (method 5005)	1, 2, 3

* PDA applies to subgroups 1 and 7.

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-M-38510.

6. NOTES

6.1 Intended use. Microcircuits conforming to this drawing are intended for use when military specifications do not exist and qualified military devices that will perform the required function are not available for OEM application. When a military specification exists and the product covered by this drawing has been qualified for listing on QPL-38510, the device specified herein will be inactivated and will not be used for new design. The QPL-38510 product shall be the preferred item for all applications.

6.2 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.

6.3 Comments. Comments on this drawing should be directed to DESC-ECS, Dayton, Ohio 45444, or telephone 513-296-5375.

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6.4 Approved source of supply. An approved source of supply is listed herein. Additional sources will be added as they become available. The vendor listed herein has agreed to this drawing and a certificate of compliance (see 3.5 herein) has been submitted to DESC-ECS.

Military drawing part number	Vendor CAGE number	Vendor similar part number <u>1/</u>
5962-8772801EX	04713	10H519/BEAJC
5962-8772801FX	04713	10H519/BFAJC
5962-87728012X	04713	10H519M/B2AJC

1/ Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

Vendor CAGE
number

04713

Vendor name
and address

Motorola, Incorporated
7402 South Price Road
Tempe, AZ 85283

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